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Counsel for Plaintiff

UNITED STATES DISTRICT COURT  
CENTRAL DISTRICT OF CALIFORNIA

\_\_\_\_\_, Individually and on  
behalf of all others similarly situated,

Plaintiff,

v.

TOWER SEMICONDUCTOR LTD.,  
RUSSELL C. ELLWANGER, and  
OREN SHIRAZI,

Defendants.

Case No:

**CLASS ACTION COMPLAINT FOR  
VIOLATIONS OF THE FEDERAL  
SECURITIES LAWS**

**JURY TRIAL DEMANDED**

Plaintiff \_\_\_\_\_ (“Plaintiff”), individually and on behalf of all other persons similarly situated, by Plaintiff’s undersigned attorneys, for Plaintiff’s Complaint against Defendants (defined below), alleges the following based upon personal knowledge as to Plaintiff and Plaintiff’s own acts, and upon information and belief as to all other matters based on the investigation conducted by and through Plaintiff’s attorneys, which included, among other things, a review of U.S. Securities and Exchange Commission (“SEC”) filings by Tower Semiconductor Ltd., (“Tower Semiconductor” or

**CLASS ACTION COMPLAINT FOR VIOLATIONS OF THE FEDERAL  
SECURITIES LAWS**

1 the “Company”), as well as media and analyst reports about the Company. Plaintiff  
2 believes that substantial evidentiary support will exist for the allegations set forth herein  
3 after a reasonable opportunity for discovery.

#### 4 **NATURE OF THE ACTION**

5 1. This is a federal securities class action on behalf of a class consisting of all  
6 persons other than Defendants who purchased the securities of Tower Semiconductor  
7 between April 30, 2012 and January 13, 2016 (the “Class Period”), inclusive, seeking to  
8 recover compensable damages caused by Defendants’ violations of federal securities  
9 laws and pursue remedies under the Securities Exchange Act of 1934 (the “Exchange  
10 Act”).

#### 11 **JURISDICTION AND VENUE**

12 2. The claims asserted herein arise under and pursuant to Sections 10(b) and  
13 20(a) of the Exchange Act, (15 U.S.C. §78j (b) and 78t (a)), and Rule 10b-5 promulgated  
14 thereunder (17 C.F.R. §240.10b-5).

15 3. This Court has jurisdiction over the subject matter of this action pursuant to  
16 §27 of the Exchange Act (15 U.S.C. §78aa) and 28 U.S.C. § 1331.

17 4. Venue is proper in this District pursuant to §27 of the Exchange Act and 28  
18 U.S.C. §1391(b) as Defendants conducts business in this district and a significant portion  
19 of the Defendants’ actions and the subsequent damages took place within this District.

20 5. In connection with the acts, conduct and other wrongs alleged in this  
21 Complaint, Defendants, directly or indirectly, used the means and instrumentalities of  
22 interstate commerce, including but not limited to, the United States mails, interstate  
23 telephone communications and the facilities of the national securities exchange.

#### 24 **PARTIES**

25 6. Plaintiff, as set forth in the accompanying certification, incorporated by  
26 reference herein, purchased Tower Semiconductor common stock at artificially inflated  
27 prices during the Class Period and has been damaged thereby.

28

1           7. Defendant Tower Semiconductor is a company incorporated under the laws  
2 of Israel and headquartered in Migdal Haemek, Israel. Defendant Tower Semiconductor  
3 is an independent specialty foundry dedicated to the manufacturing of semiconductors  
4 and operates a semiconductor fabrication facility in Newport Beach, California. Its  
5 common stock trades on the NASDAQ Stock Market (“NASDAQ”) under the ticker  
6 symbol “TSEM.”

7           8. Defendant Russell C. Ellwanger (“Ellwanger”) has served as the  
8 Company’s Chief Executive Officer and Director throughout the Class Period.

9           9. Defendant Oren Shirazi (“Shirazi”) has served as the Company’s Chief  
10 Financial Officer and Senior Vice President of Finance throughout the Class Period.

11           10. The defendants referenced above in ¶¶ 8 – 9 are sometimes referred to  
12 herein as the “Individual Defendants.”

13           11. Defendant Tower Semiconductor and the Individual Defendants are referred  
14 to herein, collectively, as the “Defendants.”

15           12. Each of the Individual Defendants:

16               (a) directly participated in the management of the Company;

17               (b) was directly involved in the day-to-day operations of the Company at  
18 the highest levels;

19               (c) was privy to confidential proprietary information concerning the  
20 Company and its business and operations;

21               (d) was involved in drafting, producing, reviewing and/or disseminating  
22 the false and misleading statements and information alleged herein;

23               (e) was aware of or recklessly disregarded the fact that the false and  
24 misleading statements were being issued concerning the Company; and

25               (f) approved or ratified these statements in violation of the federal  
26 securities laws.

27           13. As officers, directors, and controlling persons of a publicly-held company  
28 whose securities are and were registered with the SEC pursuant to the Exchange Act, and

1 was traded on NASDAQ and governed by the provisions of the federal securities laws,  
2 the Individual Defendants each had a duty to disseminate accurate and truthful  
3 information promptly with respect to the Company's business prospects and operations,  
4 and to correct any previously-issued statements that had become materially misleading  
5 or untrue to allow the market price of the Company's publicly-traded stock to reflect  
6 truthful and accurate information.

7 14. Tower Semiconductor is liable for the acts of the Individual Defendants and  
8 its employees under the doctrine of respondeat superior and common law principles of  
9 agency as all of the wrongful acts complained of herein were carried out within the scope  
10 of their employment with authorization.

11 15. The scienter of the Individual Defendants and other employees and agents  
12 of the Company is similarly imputed to Tower Semiconductor under respondeat superior  
13 and agency principles.

## 14 **SUBSTANTIVE ALLEGATIONS**

### 15 **Background**

16 16. The Company is an independent semiconductor foundry, which  
17 manufactures analog intensive mixed-signal semiconductor devices in the United States,  
18 Asia, and Europe.

19 17. In October 2010, Tower Semiconductor raised an aggregate principal  
20 amount of approximately \$100 million through the issuance of long-term debentures  
21 ("Series F Debentures"), due in two equal installments in December 2015 and December  
22 2016.

23 18. The Series F Debentures carry an interest rate of 7.8 percent per annum  
24 payable semiannually in Israeli New Sheqels ("NIS") but are fully linked to the US  
25 dollar. The Series F Debentures are convertible into Tower Semiconductor's ordinary  
26 shares during the period commencing in September 2012 and ending in December 2016,  
27 with a conversion price that shall be equal to 120% of the average trading price of Tower  
28 Semiconductor's ordinary shares on the Tel-Aviv Stock Exchange during the 15 trading

1 days before September 18, 2012, provided that in no event will the price be more than  
2 NIS 6.5, and not less than NIS 1.0.

3 19. In June 2011, the Company acquired the fabrication facility in Nishiwaki  
4 City, Hyogo, Japan owned by a wholly-owned Japanese subsidiary of Micron  
5 Technology Inc. (“Micron”) for \$63.63 million—\$40 million in cash and \$22.63 million  
6 in the issuance of 19.7 million ordinary shares of Tower Semiconductor. The Company  
7 operates this facility through its wholly-owned Japanese subsidiary, TowerJazz Japan  
8 Ltd. (“TJP”).

9 20. In February 2012, Tower Semiconductor raised approximately \$80 million  
10 through the expansion of its long-term outstanding Series F Debentures.

11 21. In March 2014, the Company acquired a 51% equity stake in TowerJazz  
12 Panasonic Semiconductor Co., Ltd. (“TPSCo”), which was formed by Panasonic  
13 Corporation (“Panasonic”) to manufacture products for Panasonic and potentially other  
14 third parties, using Panasonic’s three semiconductor manufacturing facilities located in  
15 Hokuriku, Japan for 870,454 of the Company’s ordinary shares valued at approximately  
16 \$7.4 million.

17 22. In 2014, the operations of TJP in the Nishiwaki facility ceased in the course  
18 of a restructuring of the Company’s activities and business in Japan.

19 **Materially False And Misleading Statements**

20 23. The Class Period begins on April 30, 2012, when the Company filed its  
21 annual report on Form 20-F for the year ending December 31, 2011 (the “2011 20-F”)   
22 with the SEC, which contained the Company’s financial results for the year ending  
23 December 31, 2011. The 2011 20-F was signed by Defendant Ellwanger. The 2011 20-F  
24 contained signed certifications pursuant to the Sarbanes-Oxley Act of 2002 (“SOX”) by  
25 Defendants Ellwanger and Shirazi attesting to the accuracy of financial reporting.

26 24. The 2011 20-F stated the following with regards to the acquisition of TJP:

27 Acquisition of TJP  
28

1 The fair value of the consideration the Company paid for TJP was \$62.6  
2 million, of which \$40 million was paid in cash and \$22.6 million was paid  
3 through the issuance to Micron of approximately 19.7 million ordinary  
4 shares of Tower. The costs incurred in connection with the acquisition were  
\$1.5 million and are included in operating expenses.

5 The purchase price has been allocated on the basis of the estimated fair  
6 value of the assets purchased and the liabilities assumed. The estimated fair  
7 value of the assets, net amounted to \$82 million. As the purchase price was  
8 less than the fair value of net assets, the Company recognized a gross gain  
on the acquisition of \$19.5 million.

9 Net profit for the year ended December 31, 2011 includes approximately  
10 \$10.1 million net positive effect from the acquisition, comprised of (i)  
11 approximately \$19.5 million gross gain from the acquisition, and (ii)  
12 approximately \$9.4 million of related tax provisions and other expenses  
directly associated with this acquisition.

13 The Company believes that the lower than fair asset value paid by for TJP  
14 and the resultant gain realized from the acquisition derived from (i)  
15 declining forecast and weakening demand for products currently  
16 manufactured by TJP, (ii) the fact that an acquisition of a fab as a whole is  
17 less costly than acquiring each fab component separately, (iii) limited  
18 opportunities to sell a fab while maintaining the employment level, and (iv)  
the natural disasters in Japan which occurred in March 2011.

19 The allocation of fair value to the assets acquired and liabilities assumed is  
20 as follows ( in thousands):

	As of June 3, 2011
21 Current assets	\$ 25,783
22 Property, plant, and equipment, including real estate	145,559
23 Intangible assets	11,156
24 Other assets	2,900
25 Total assets as of acquisition date	185,398
26	
27 Current liabilities	28,317
28 Long-term liabilities (mainly employees related termination benefits)	<u>74,984</u>

1	Total liabilities as of acquisition date	103,301
2	Net assets as of acquisition date	\$ 82,097

3 The fair values set forth above are based on a valuation of TJP assets and  
4 liabilities performed by third party professional valuation experts hired to  
5 appraise the fair value of the assets in accordance with ASC 805-“Business  
6 Combinations”.

7 In addition, as part of said acquisition, TJP entered into a supply agreement  
8 with Micron. In accordance with this agreement, TJP will manufacture  
9 products for Micron at the Nishiwaki facility for at least three years with  
10 process technologies licensed from Micron under a technology licensing  
11 agreement signed between the companies at the closing of the acquisition.  
12 Under the supply agreement Micron is committed to purchase certain  
13 minimum volumes, with periodic downward scaling of quantities, until the  
14 end of the second quarter of 2014. The companies also agreed to provide  
15 each other with transition services required for the duration of the transition  
16 period of approximately two to three years.

17 In order to ensure continued supply of wafers to Micron, Tower and Micron  
18 also executed a credit support agreement pursuant to which Tower and TJP,  
19 are subject to certain covenants and other protections until June 2013.

20 Tower's ordinary shares issued to Micron are subject to lock-up  
21 arrangement with releases of 25% of the shares every six months ending on  
22 June 2013.

23 For further details regarding the acquisition of TJP, see Note 3 to the annual  
24 consolidated financial statements for the year ended December 31, 2011.

25 25. On April 30, 2013, the Company filed its annual report on Form 20-F for  
26 the year ending December 31, 2012 (the “2012 20-F”) with the SEC, which contained  
27 the Company’s financial results for the year ending December 31, 2012. The 2012 20-F  
28 was signed by Defendant Ellwanger. The 2012 20-F contained signed SOX certifications  
by Defendant Ellwanger and Shirazi attesting to the accuracy of financial reporting.

26. The 2012 20-F stated the following with regards to the acquisition of TJP:

Acquisition of TJP

1 The fair value of the consideration the Company paid for TJP was \$62.6  
2 million, of which \$40 million was paid in cash and \$22.6 million was paid  
3 through the issuance to Micron of approximately 1.3 million ordinary  
4 shares of Tower. The costs incurred in connection with the acquisition were  
5 \$1.5 million and are included in operating expenses.

6 The purchase price has been allocated on the basis of the estimated fair  
7 value of the assets purchased and the liabilities assumed. The estimated fair  
8 value of the assets, net amounted to \$82 million. As the purchase price was  
9 less than the fair value of the net assets, the Company recognized a gross  
gain on the acquisition of \$19.5 million.

10 Net profit for the year ended December 31, 2011, includes approximately  
11 \$10.1 million net positive effect from the acquisition, comprised of (i)  
12 approximately \$19.5 million gross gain from the acquisition, and (ii)  
13 approximately \$9.4 million of related tax provisions and other expenses  
directly associated with this acquisition.

14 The Company believes that the lower than fair asset value paid by the  
15 Company for TJP and the resultant gain realized from the acquisition  
16 derived from (i) declining forecast and weakening demand for products  
17 currently manufactured by TJP, (ii) the fact that an acquisition of a fab as a  
18 whole is less costly than acquiring each fab component separately, (iii)  
19 limited opportunities to sell a fab while maintaining the employment level,  
and (iv) the natural disasters in Japan which occurred in March 2011.

20 The allocation of fair value to the assets acquired and liabilities assumed is  
21 as follows in thousands):

	As of June 3, 2011
22 Current assets	\$ 25,783
23 Property, plant, and equipment, including real estate	145,559
24 Intangible assets	11,156
25 Other assets	2,900
26 Total assets as of acquisition date	185,398
27	
28 Current liabilities	28,317

1	Long-term liabilities (mainly employees related termination benefits)	74,984
2	Total liabilities as of acquisition date	103,301
3	Net assets as of acquisition date	\$ 82,097

4 The fair values set forth above are based on a valuation of TJP assets and  
5 liabilities performed by third party professional valuation experts hired to  
6 appraise the fair value of the assets in accordance with ASC 805-“Business  
7 Combinations”.

8 In addition, as part of said acquisition, TJP entered into a supply agreement  
9 with Micron. In accordance with this agreement, TJP will manufacture  
10 products for Micron at the Nishiwaki facility for at least three years with  
11 process technologies licensed from Micron under a technology licensing  
12 agreement signed between the companies at the closing of the acquisition.  
13 Under the supply agreement, Micron is committed to purchase certain  
14 minimum volumes, with periodic downward scaling of quantities, until the  
15 end of the second quarter of 2014 with a take-or-pay provision. The  
16 companies also agreed to provide each other with transition services  
17 required for the duration of the transition period of approximately two to  
18 three years.

19 In order to ensure continued supply of wafers to Micron, Tower and Micron  
20 also executed a credit support agreement pursuant to which Tower and TJP,  
21 are subject to certain covenants and other undertakings until June 2013.

22 Tower's ordinary shares issued to Micron are subject to a lock-up  
23 arrangement with releases of 25% of the shares every six months ending in  
24 June 2013.

25 For further details regarding the acquisition of TJP, see Note 3 to the annual  
26 consolidated financial statements for the year ended December 31, 2012.

27 27. The 2012 20-F stated the following with regards the debt maturity of the  
28 Series F Debentures:

NOTE 13 - DEBENTURES

A. Composition by repayment schedule (carrying amount):

	Interest rate	2013	2014	2015	2016
Debentures Series D	8%	\$ 5,823	\$ 5,823	\$ 5,823	\$ 5,823
Debentures Series F	7.8%	--	--	50,954	50,954
Jazz's New Notes (as defined in G below)	8%	--	--	74,585	--
		<u>\$ 5,823</u>	<u>\$ 5,823</u>	<u>\$131,362</u>	<u>\$ 56,777</u>

The outstanding principal amounts of Tower debentures as of December 31, 2012 and 2011 were \$255,879 and \$177,249, respectively.

28. On May 14, 2014, the Company filed its annual report on Form 20-F for the year ending December 31, 2013 (the "2013 20-F") with the SEC, which contained the Company's financial results for the year ending December 31, 2013. The 2013 20-F was signed by Defendant Ellwanger. The 2013 20-F contained signed SOX certifications by Defendant Ellwanger and Shirazi attesting to the accuracy of financial reporting.

29. The 2013 20-F stated the following with regards to the acquisition of TJP:

#### NOTE 3 - ACQUISITION OF NISHIWAKI FAB IN JAPAN

On June 3, 2011, the Company acquired the fabrication facility in Nishiwaki City, Hyogo, Japan owned by a wholly owned Japanese subsidiary of Micron Technology Inc. ("Micron"). The acquisition was effected through a new wholly owned Japanese subsidiary of the Company, which acquired the shares of and subsequently merged with Micron's Japanese subsidiary that held the assets of the fabrication facility and related business. The merged entity is named TowerJazz Japan Ltd. ("TJP").

The fair value of the consideration the Company paid was \$62,630, of which \$40,000 was paid in cash and \$22,630 was paid through the issuance to Micron of 1.3 million ordinary shares of Tower. The costs incurred in connection with the acquisition were \$1,493 and are included in operating expenses.

1 The purchase price has been allocated on the basis of the estimated fair  
2 value of the assets purchased and the liabilities assumed. The estimated fair  
3 value of the assets, net amounted to \$82,097. As the purchase price was less  
4 than the fair value of net assets, the Company recognized a gross gain on  
the acquisition of \$19,467.

5 Net profit for the year ended December 31, 2011 includes \$10,078 net  
6 positive effect from the acquisition, comprised of (i) \$19,467 gross gain  
7 from the acquisition, and (ii) \$9,389 of related tax provisions and other  
8 expenses directly associated with this acquisition.

9 The Company believes that the gain realized from the acquisition derived  
10 from (i) declining forecast and weakening demand for products  
11 manufactured by TJP, (ii) the fact that an acquisition of a fab as a whole is  
12 less costly than acquiring each fab component separately, (iii) limited  
opportunities to sell a fab while maintaining the employment level, and (iv)  
the natural disasters in Japan which occurred in March 2011.

13 The allocation of fair value to the assets acquired and liabilities assumed is  
14 as follows:

	As of June 3, 2011
15 Current assets	\$ 25,783
16 Property, plant, and equipment, including real estate	145,559
17 Intangible assets	11,156
18 Other assets	2,900
19 Total assets as of acquisition date	185,398
20	
21 Current liabilities	28,317
22 Long-term liabilities (mainly employees related termination benefits)	74,984
23 Total liabilities as of acquisition date	103,301
24 Net assets as of acquisition date	<u>\$ 82,097</u>

25 The fair values set forth above are based on a valuation of TJP assets and  
26 liabilities performed by third party professional valuation experts hired by  
27 the Company to appraise the fair value of the assets in accordance with  
28 ASC 805 - "Business Combinations".

1 30. The 2013 20-F stated the following with regards the debt maturity of the  
2 Series F Debentures:

3 NOTE 13 - DEBENTURES  
4

5 A. Composition by repayment schedule (carrying amount):

6 As of December 31, 2013

	Interest				
	rate	2014	2015	2016	
7					
8	Debtentures Series D	8%	\$6,441	\$ 6,441	\$ 6,441
9	Debtentures Series F	7.8%	--	57,041	57,041
10	Jazz's 2010 Notes (as defined in D below)	8%	--	81,181	--
11			<u>\$6,441</u>	<u>\$144,663</u>	<u>\$63,482</u>

12 The outstanding principal amounts of the debentures as of December 31,  
13 2013 and 2012 were, approximately \$345,000 and \$349,000, respectively.

14 The Tower debentures and interest thereon are unsecured and subordinated  
15 to Tower's existing and future secured indebtedness, including indebtedness  
16 to the Israeli Banks under the Facility Agreement - see Note 16A(1), and to  
17 the government of Israel - see Note 8B. For details in regards to Jazz Notes,  
18 see D below.

19 If on a payment date of the principal or interest on any series of the Tower  
20 debentures, there is a breach of certain covenants and conditions under the  
21 Facility Agreement, the dates for payment of interest and principal on the  
22 debentures may be postponed until such covenant or condition is satisfied.

23 31. On May 14, 2015, the Company filed its annual report on Form 20-F for the  
24 year ending December 31, 2014 (the "2014 20-F") with the SEC, which contained the  
25 Company's financial results for the year ending December 31, 2014. The 2014 20-F was  
26 signed by Defendant Ellwanger. The 2014 20-F contained signed SOX certifications by  
27 Defendant Ellwanger and Shirazi attesting to the accuracy of financial reporting.

28 32. The 2014 20-F stated the following with regards to the acquisition of  
TPSCo:

1 NOTE 3 - TOWERJAZZ PANASONIC SEMICONDUCTOR CO., LTD.  
2 ESTABLISHMENT

3 Pursuant to agreements signed between Panasonic Corporation  
4 (“Panasonic”) and Tower, Panasonic formed a fully-owned subsidiary  
5 named TPSCo in March 2014. Further to said agreements, (a) Panasonic  
6 transferred licenses use rights of its semiconductor wafer manufacturing  
7 process and transferred its capacity tools of 8 inch and 12 inch at three of its  
8 fabs located in Hokuriku Japan (Uozu, Tonami and Arai) to TPSCo; and (b)  
9 Tower acquired 51% of the shares of TPSCo in consideration for the  
10 issuance of ordinary shares of Tower to Panasonic valued at approximately  
11 \$7,411.

12 The purchase price has been allocated on the basis of the estimated fair  
13 value of the assets purchased and the liabilities assumed. The estimated fair  
14 value of the assets, net amounted to \$180,935. As the fair value of the net  
15 assets acquired less the non-controlling interest exceeded the purchase  
16 price, Tower recognized a gain on the acquisition in the amount of  
17 \$166,404.

18 The Company believes that the gain realized from the acquisition mainly  
19 derived from the fact that Panasonic’s fabs were not fully utilized in recent  
20 years and were anticipated to remain so in the coming years, hence any  
21 volume manufacturing and revenue resulting from the transaction with  
22 Tower, due to Tower’s customer base, contacts, technologies and foundry  
23 management and operations expertise will benefit Panasonic and directly  
24 increase the value of the transferred assets.

25 The allocation of fair value to the assets acquired and liabilities assumed is  
26 as follows:

	As of March 31, 2014
Current assets	\$ 91,414
Machinery and equipment	245,278
Intangible assets	24,520
Total assets as of acquisition date	\$ 361,212

1	Current liabilities	\$ 1,426
2	Long-term Loan	85,249
3	Deferred tax liability	93,602
4	Total liabilities as of acquisition date	\$ 180,277
5	Total net assets acquired	\$ 180,935
6	The fair value non-controlling interests in TPSCo	7,120
7	Tower's consideration	7,411
8	Gain on acquisition	\$ 166,404

9 The fair value of the non-controlling interest in the table above was derived  
10 based on the purchase price paid by Tower to Panasonic in consideration  
11 for the acquisition of 51% of TPSCo's shares.

12 The fair values set forth above are based on a valuation of TPSCo's assets  
13 and liabilities performed by third party professional valuation experts hired  
14 by the Company to appraise the fair value of the assets in accordance with  
15 ASC 805-10 "Business Combinations".

16 TPSCo, Tower and Panasonic also agreed to the following, among others:  
17 (i) a five-year manufacturing agreement between Panasonic and TPSCo,  
18 under which Panasonic will acquire products from TPSCo; (ii) a five-year  
19 production related and complimentary services agreement between  
20 Panasonic and TPSCo, under which Panasonic will acquire services from  
21 TPSCo; (iii) TPSCo will license certain technologies from Panasonic in  
22 order to utilize certain Panasonic process technologies for the  
23 manufacturing of products; (iv) Panasonic will provide TPSCo with various  
24 transition services and support; (v) TPSCo will lease the manufacturing  
25 buildings and related facilities infrastructure from Panasonic; and (iv)  
26 TPSCo will receive services from Tower including marketing, sales,  
27 general and administration services.

28 Pro forma financial information is not presented since the financial  
information of the acquire was prepared for internal use within its group  
and is not representative of the financial statements of the acquire had it  
been standalone entity.

33. The 2014 20-F stated the following with regards the debt maturity of the Series F Debentures:

NOTE 13 - DEBENTURES

A. Composition by repayment schedule (carrying amount):

	As of December 31, 2014				
	Interest rate	2015	2016	2017	2018
Debentures Series D	8%	\$ 5,796	\$ 5,796	\$ --	\$ --
Debentures Series F	7.8%	58,626	58,626	--	--
Jazz's 2010 Notes (as defined in D below)	8%	45,577	--	--	--
Jazz's 2014 Notes (as defined in E below)	8%	--	--	--	42,889
					42,889
		<u>\$109,999</u>	<u>\$64,422</u>	<u>\$ --</u>	<u>\$ --</u>

The outstanding principal amounts of the debentures as of December 31, 2014 and 2013 were approximately \$312,000 and \$345,000, respectively, and following redemption of Jazz 2010 Notes described in D below and conversions of Series F described in C below, the outstanding principal amounts of all the company's debentures has been reduced to approximately \$208,000 as of February 15, 2015.

Tower debentures and interest thereon are unsecured and subordinated to Tower's existing and future secured indebtedness, including indebtedness to the Israeli Banks under the Facility Agreement, see Note 16A(1), and to the government of Israel, see Note 8B. For details in regards to Jazz Notes, see E below.

If on a payment date of the principal or interest on any series of the Tower debentures, there is a breach of certain covenants and conditions under the Facility Agreement, the dates for payment of interest and principal on the debentures may be postponed until such covenant or condition is satisfied.



1 otherwise acquired Tower Semiconductor securities during the Class Period (the  
2 “Class”); and were damaged upon the revelation of the alleged corrective disclosure.  
3 Excluded from the Class are Defendants herein, the officers and directors of the  
4 Company, at all relevant times, members of their immediate families and their legal  
5 representatives, heirs, successors or assigns and any entity in which Defendants have or  
6 had a controlling interest.

7 39. The members of the Class are so numerous that joinder of all members is  
8 impracticable. Throughout the Class Period, Tower Semiconductor securities were  
9 actively traded on the NASDAQ. While the exact number of Class members is unknown  
10 to Plaintiff at this time and can be ascertained only through appropriate discovery,  
11 Plaintiff believes that there are hundreds or thousands of members in the proposed Class.  
12 Record owners and other members of the Class may be identified from records  
13 maintained by Tower Semiconductor or its transfer agent and may be notified of the  
14 pendency of this action by mail, using the form of notice similar to that customarily used  
15 in securities class actions.

16 40. Plaintiff’s claims are typical of the claims of the members of the Class as all  
17 members of the Class are similarly affected by Defendants’ wrongful conduct in  
18 violation of federal law that is complained of herein.

19 41. Plaintiff will fairly and adequately protect the interests of the members of  
20 the Class and has retained counsel competent and experienced in class and securities  
21 litigation. Plaintiff has no interests antagonistic to or in conflict with those of the Class.

22 42. Common questions of law and fact exist as to all members of the Class and  
23 predominate over any questions solely affecting individual members of the Class.  
24 Among the questions of law and fact common to the Class are:

- 25 • whether the federal securities laws were violated by Defendants’ acts as  
26 alleged herein;

- 1 • whether statements made by Defendants to the investing public during the
- 2 Class Period misrepresented material facts about the business, operations
- 3 and management of Tower Semiconductor;
- 4 • whether the Individual Defendants caused Tower Semiconductor to issue
- 5 false and misleading financial statements during the Class Period;
- 6 • whether Defendants acted knowingly or recklessly in issuing false and
- 7 misleading financial statements;
- 8 • whether the prices of Tower Semiconductor securities during the Class
- 9 Period were artificially inflated because of the Defendants' conduct
- 10 complained of herein; and
- 11 • whether the members of the Class have sustained damages and, if so, what
- 12 is the proper measure of damages.

13 43. A class action is superior to all other available methods for the fair and  
14 efficient adjudication of this controversy since joinder of all members is impracticable.  
15 Furthermore, as the damages suffered by individual Class members may be relatively  
16 small, the expense and burden of individual litigation make it impossible for members of  
17 the Class to individually redress the wrongs done to them. There will be no difficulty in  
18 the management of this action as a class action.

19 44. Plaintiff will rely, in part, upon the presumption of reliance established by  
20 the fraud-on-the-market doctrine in that:

- 21 • Defendants made public misrepresentations or failed to disclose material
- 22 facts during the Class Period;
- 23 • the omissions and misrepresentations were material;
- 24 • Tower Semiconductor securities are traded in an efficient market;
- 25 • the Company's shares were liquid and traded with moderate to heavy
- 26 volume during the Class Period;
- 27 • the Company traded on the NASDAQ and was covered by multiple
- 28 analysts;

- 1 • the misrepresentations and omissions alleged would tend to induce a
- 2 reasonable investor to misjudge the value of the Company's securities; and
- 3 • Plaintiff and members of the Class purchased, acquired and/or sold Tower
- 4 Semiconductor securities between the time the Defendants failed to disclose
- 5 or misrepresented material facts and the time the true facts were disclosed,
- 6 without knowledge of the omitted or misrepresented facts.

7 45. Based upon the foregoing, Plaintiff and the members of the Class are  
8 entitled to a presumption of reliance upon the integrity of the market.

9 46. Alternatively, Plaintiff and the members of the Class are entitled to the  
10 presumption of reliance established by the Supreme Court in *Affiliated Ute Citizens of*  
11 *the State of Utah v. United States*, 406 U.S. 128, 92 S. Ct. 2430 (1972), as Defendants  
12 omitted material information in their Class Period statements in violation of a duty to  
13 disclose such information, as detailed above.

### 14 **COUNT I**

#### 15 **Violations of Section 10(b) of The Exchange Act and Rule 10b-5** 16 **Against All Defendants**

17 47. Plaintiff repeats and realleges each and every allegation contained above as  
18 if fully set forth herein.

19 48. This Count is asserted against Defendants and is based upon Section 10(b)  
20 of the Exchange Act, 15 U.S.C. § 78j(b), and Rule 10b-5 promulgated thereunder by the  
21 SEC.

22 49. During the Class Period, Defendants engaged in a plan, scheme, conspiracy  
23 and course of conduct, pursuant to which they knowingly or recklessly engaged in acts,  
24 transactions, practices and courses of business which operated as a fraud and deceit upon  
25 Plaintiff and the other members of the Class; made various untrue statements of material  
26 facts and omitted to state material facts necessary in order to make the statements made,  
27 in light of the circumstances under which they were made, not misleading; and employed  
28 devices, schemes and artifices to defraud in connection with the purchase and sale of

1 securities. Such scheme was intended to, and, throughout the Class Period, did: (i)  
2 deceive the investing public, including Plaintiff and other Class members, as alleged  
3 herein; (ii) artificially inflate and maintain the market price of Tower Semiconductor  
4 securities; and (iii) cause Plaintiff and other members of the Class to purchase or  
5 otherwise acquire Tower Semiconductor securities at artificially inflated prices. In  
6 furtherance of this unlawful scheme, plan and course of conduct, Defendants, and each  
7 of them, took the actions set forth herein.

8         50. Pursuant to the above plan, scheme, conspiracy and course of conduct, each  
9 of the Defendants participated directly or indirectly in the preparation and/or issuance of  
10 the annual reports, SEC filings, press releases and other statements and documents  
11 described above, including statements made to securities analysts and the media that  
12 were designed to influence the market for Tower Semiconductor securities. Such reports,  
13 filings, releases and statements were materially false and misleading in that they failed to  
14 disclose material adverse information and misrepresented the truth about Tower  
15 Semiconductor' disclosure controls and procedures.

16         51. By virtue of their positions at Tower Semiconductor, Defendants had actual  
17 knowledge of the materially false and misleading statements and material omissions  
18 alleged herein and intended thereby to deceive Plaintiff and the other members of the  
19 Class, or, in the alternative, Defendants acted with reckless disregard for the truth in that  
20 they failed or refused to ascertain and disclose such facts as would reveal the materially  
21 false and misleading nature of the statements made, although such facts were readily  
22 available to Defendants. Said acts and omissions of Defendants were committed  
23 willfully or with reckless disregard for the truth. In addition, each defendant knew or  
24 recklessly disregarded that material facts were being misrepresented or omitted as  
25 described above.

26         52. Information showing that Defendants acted knowingly or with reckless  
27 disregard for the truth is peculiarly within Defendants' knowledge and control. As the  
28

1 senior managers and/or directors of Tower Semiconductor, the Individual Defendants  
2 had knowledge of the details of Tower Semiconductor' internal affairs.

3 53. The Individual Defendants are liable both directly and indirectly for the  
4 wrongs complained of herein. Because of their positions of control and authority, the  
5 Individual Defendants were able to and did, directly or indirectly, control the content of  
6 the statements of Tower Semiconductor. As officers and/or directors of a publicly-held  
7 company, the Individual Defendants had a duty to disseminate timely, accurate, and  
8 truthful information with respect to Tower Semiconductor' businesses, operations, future  
9 financial condition and future prospects. As a result of the dissemination of the  
10 aforementioned false and misleading reports, releases and public statements, the market  
11 price of Tower Semiconductor securities was artificially inflated throughout the Class  
12 Period. In ignorance of the adverse facts concerning Tower Semiconductor' business and  
13 financial condition which were concealed by Defendants, Plaintiff and the other  
14 members of the Class purchased or otherwise acquired Tower Semiconductor securities  
15 at artificially inflated prices and relied upon the price of the securities, the integrity of  
16 the market for the securities and/or upon statements disseminated by Defendants, and  
17 were damaged thereby.

18 54. During the Class Period, Tower Semiconductor securities were traded on an  
19 active and efficient market. Plaintiff and the other members of the Class, relying on the  
20 materially false and misleading statements described herein, which the Defendants made,  
21 issued or caused to be disseminated, or relying upon the integrity of the market,  
22 purchased or otherwise acquired shares of Tower Semiconductor securities at prices  
23 artificially inflated by Defendants' wrongful conduct. Had Plaintiff and the other  
24 members of the Class known the truth, they would not have purchased or otherwise  
25 acquired said securities, or would not have purchased or otherwise acquired them at the  
26 inflated prices that were paid. At the time of the purchases and/or acquisitions by  
27 Plaintiff and the Class, the true value of Tower Semiconductor securities was  
28 substantially lower than the prices paid by Plaintiff and the other members of the Class.

1 The market price of Tower Semiconductor securities declined sharply upon public  
2 disclosure of the facts alleged herein to the injury of Plaintiff and Class members.

3 55. By reason of the conduct alleged herein, Defendants knowingly or  
4 recklessly, directly or indirectly, have violated Section 10(b) of the Exchange Act and  
5 Rule 10b-5 promulgated thereunder.

6 56. As a direct and proximate result of Defendants' wrongful conduct, Plaintiff  
7 and the other members of the Class suffered damages in connection with their respective  
8 purchases, acquisitions and sales of the Company's securities during the Class Period,  
9 upon the disclosure that the Company had been disseminating misrepresented financial  
10 statements to the investing public.

11 **COUNT II**

12 **Violations of Section 20(a) of The Exchange Act**  
13 **Against The Individual Defendants**

14 57. Plaintiff repeats and realleges each and every allegation contained in the  
15 foregoing paragraphs as if fully set forth herein.

16 58. During the Class Period, the Individual Defendants participated in the  
17 operation and management of Tower Semiconductor, and conducted and participated,  
18 directly and indirectly, in the conduct of Tower Semiconductor's business affairs.  
19 Because of their senior positions, they knew the adverse non-public information about  
20 Tower Semiconductor' operations, current financial position and future business  
21 prospects.

22 59. As officers and/or directors of a publicly owned company, the Individual  
23 Defendants had a duty to disseminate accurate and truthful information with respect to  
24 Tower Semiconductor' business practices, and to correct promptly any public statements  
25 issued by Tower Semiconductor which had become materially false or misleading.

26 60. Because of their positions of control and authority as senior officers, the  
27 Individual Defendants were able to, and did, control the contents of the various reports,  
28 press releases and public filings which Tower Semiconductor disseminated in the



1 D. Awarding such other and further relief as this Court may deem just and  
2 proper.

3 **DEMAND FOR TRIAL BY JURY**

4 Plaintiff hereby demands a trial by jury.

5  
6 Dated: January \_\_, 2016

Respectfully submitted,

7 **THE ROSEN LAW FIRM, P.A.**

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